NSN 5961-01-291-0821

Demilitarization:

No Fiig: A110a0

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-291-0821 **Inclosure Material:** Ceramic or glass or metal **Overall Length:** Between 0.417 inches and 0.440 inches **Overall Height:** Between 0.060 inches and 0.100 inches Overall Width: Between 0.280 inches and 0.350 inches **Component Name And Quantity:** 4 semiconductor device diode **Mounting Method:** Press fit **Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 0.88 forward voltage, dc all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Test Data Document:** 04939-717801320 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 20 printed circuit Shelf Life: N/a **Unit Of Measure:**